

R-C Thermal Model Parameters

DESCRIPTION

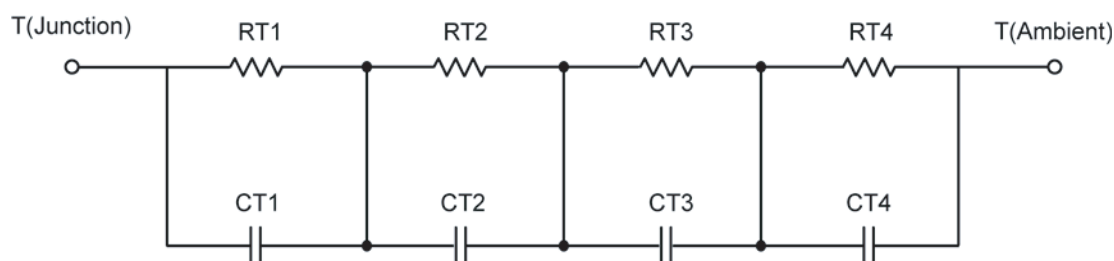
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION					
Thermal Resistance (°C/W)					
Junction to	Ambient Nch	Ambient Pch	Case	Foot Nch	Foot Pch
RT1	18.8723	16.6933	N/A	11.0937	12.7957
RT2	8.7985	7.5970	N/A	2.7173	3.7553
RT3	26.8668	28.1882	N/A	14.2007	11.7384
RT4	54.9607	57.4171	N/A	11.9112	11.6561
Thermal Capacitance (Joules/°C)					
Junction to	Ambient Nch	Ambient Pch	Case	Foot Nch	Foot Pch
CT1	12.9669 m	23.2467 m	N/A	5.9662 m	4.2529 m
CT2	3.3110 m	970.0034 u	N/A	845.9260 u	511.3149 u
CT3	56.7398 m	44.7215 m	N/A	15.0022 m	33.9748 m
CT4	1.1690	1.2124	N/A	166.9101 m	130.9698 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)					
Junction to	Ambient Nch	Ambient Pch	Case	Foot Nch	Foot Pch
RT1	6.6538	6.1531	N/A	5.5258	5.2134
RT2	25.6696	23.1988	N/A	20.6873	19.9882
RT3	24.1929	25.6127	N/A	8.2291	9.5257
RT4	53.0059	54.6507	N/A	5.4518	5.2791
Thermal Capacitance (Joules/°C)					
Junction to	Ambient Nch	Ambient Pch	Case	Foot Nch	Foot Pch
CT1	1.2523 m	455.1067 u	N/A	1.0313 m	380.8703 u
CT2	6.1023 m	9.6892 m	N/A	4.2548 m	4.7932 m
CT3	46.9702 m	34.5765 m	N/A	58.6845 m	64.0459 m
CT4	1.1277	1.2216	N/A	334.8835 m	87.5032 m

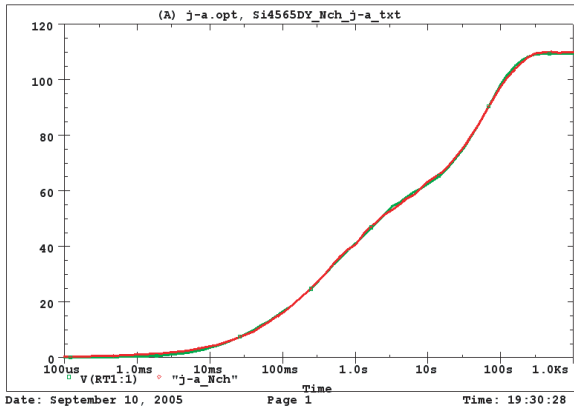
Note: NA indicates not applicable

Reference:

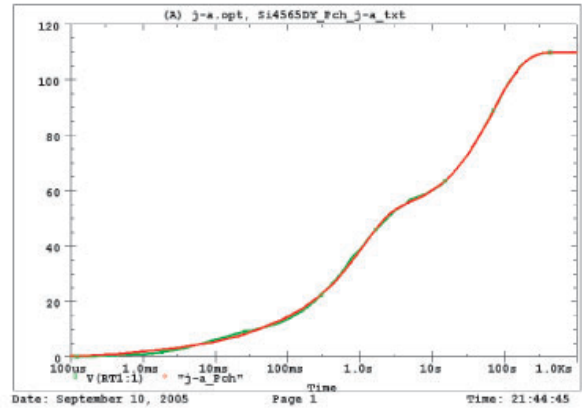
[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002



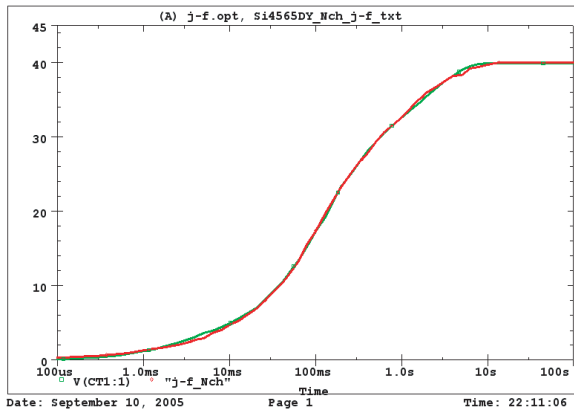
Si4565DY Tank j-a_Nch Temperature: 27.0



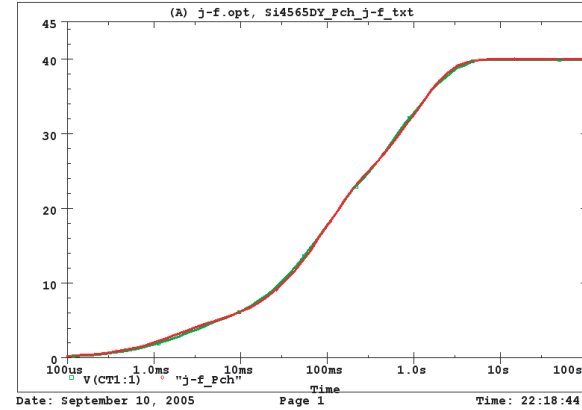
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Si4565DY Tank j-f_Nch Temperature: 27.0

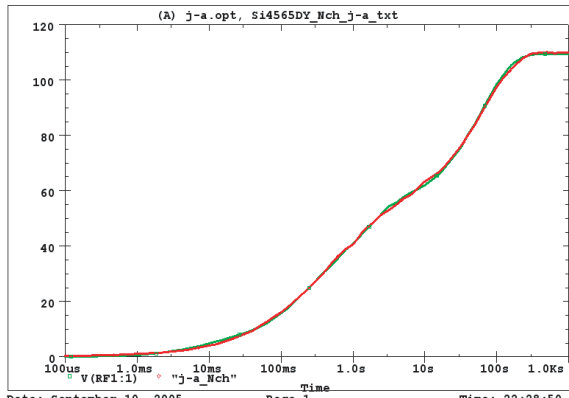


Si4565DY Tank j-f_Pch Temperature: 27.0

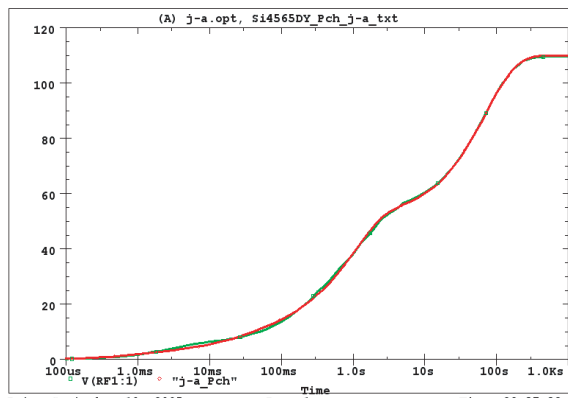




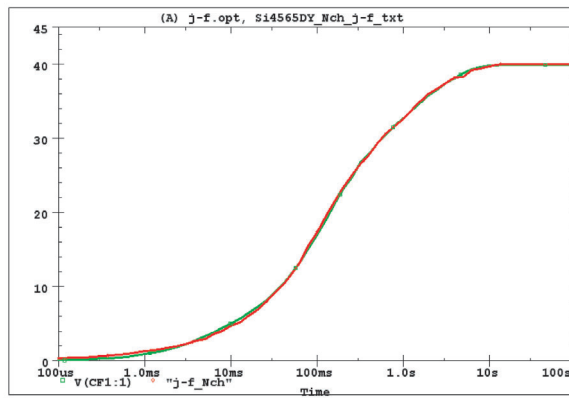
Si4565DY Filter j-a_Nch Temperature: 27.0



Si4565DY Filter j-a_Pch Temperature: 27.0



Si4565DY Filter j-f_Nch Temperature: 27.0



Si4565DY Filter j-f_Pch Temperature: 27.0

